

The PE42427 is a HaRP[™] technology-enhanced SPDT

voltage CMOS-compatible control interface and requires

pSemi's HaRP technology enhancements deliver high

performance superior to GaAs with the economy and

linearity and exceptional harmonics performance. It is an

innovative feature of the UltraCMOS[®] process, providing

applications from 5-6000 MHz. This reflective switch

integrates on-board CMOS control logic with a low

RF switch designed to cover a broad range of

Product Description

no external components.

integration of conventional CMOS.

Product Specification

PE42427

UltraCMOS[®] SPDT RF Switch 5-6000 MHz

Features

- Symmetric SPDT reflective switch
- Low insertion loss
 - 0.23 dB typical @ 100 MHz
 - 0.25 dB typical @ 1000 MHz
 - 0.40 dB typical @ 3000 MHz
 - 0.65 dB typical @ 5000 MHz
 - 0.90 dB typical @ 6000 MHz
- Low spurious performance of -163 dBm/Hz
- Wide supply range of 2.3-5.5V
- Excellent linearity
 - IIP2 of 105 dBm @ 17 MHz
 - IIP3 of 81 dBm @ 17 MHz
- High ESD tolerance
 - 4 kV HBM on RF pins to GND
 - 1 kV on all other pins
- Logic Select (LS) pin provides maximum flexibility of control logic
- 12-lead 2 × 2 mm QFN package

Figure 1. Functional Diagram

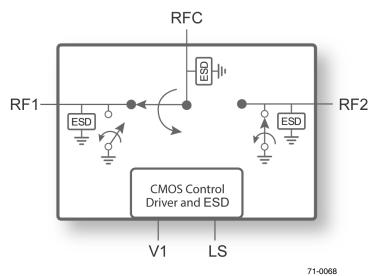


Figure 2. Package Type

12-lead 2 x 2 x 0.55 mm QFN





Table 1. Electrical Specifications @ +25 °C¹, V_{DD} = 2.3-5.5V (Z_S = Z_L = 50 Ω), unless otherwise specified

| Parameter | Path | Condition | Min | Тур | Max | Unit |
|-----------------------------|---------|--|-----|-----------------|-------------------|------|
| Operational frequency | | | 5 | | 6000 | MHz |
| | | 5-100 MHz | | 0.23 | | dB |
| | | 100-1000 MHz | | 0.25 | 0.35 | dB |
| | | 1000-2000 MHz | | 0.30 | 0.40 | dB |
| Insertion loss ² | RFX-RFC | 2000-3000 MHz | | 0.40 | 0.50 | dB |
| | | 3000-4000 MHz | | 0.50 | 0.70 | dB |
| | | 4000-5000 MHz | | 0.65 | 0.90 ² | dB |
| | | 5000-6000 MHz | | 0.90 | 1.25 ² | dB |
| | | 5-100 MHz | | 68 | | dB |
| | | 100-1000 MHz | 42 | 44 | | dB |
| | | 1000-2000 MHz | 33 | 35 | | dB |
| Isolation | RFX-RFC | 2000-3000 MHz | 27 | 29 | | dB |
| | | 3000-4000 MHz | 22 | 24 | | dB |
| | | 4000-5000 MHz | 18 | 20 | | dB |
| | | 5000-6000 MHz | 15 | 17 | | dB |
| | RFX-RFX | 5-100 MHz | | 61 | | dB |
| | | 100-1000 MHz | 40 | 41 | | dB |
| | | 1000-2000 MHz | 32 | 33 | | dB |
| Isolation | | 2000-3000 MHz | 26 | 28 | | dB |
| | | 3000-4000 MHz | 22 | 24 | | dB |
| | | 4000-5000 MHz | 18 | 20 | | dB |
| | | 5000-6000 MHz | 15 | 16 | | dB |
| | | 5-100 MHz | | 33 | | dB |
| | | 100-1000 MHz | | 28 | | dB |
| | RFX-RFC | 1000-2000 MHz | | 21 | | dB |
| Return loss ² | | 2000-3000 MHz | | 20 | | dB |
| | | 3000-4000 MHz | | 18 | | dB |
| | | 4000-5000 MHz | | 16 ² | | dB |
| | | 5000-6000 MHz | | 13 ² | | dB |
| | | +18 dBm input power, 17-204 MHz | | -92 | | dBc |
| 2nd harmonic | RFX-RFC | +32 dBm output power, 850 / 900 MHz | | -99 | | dBc |
| | | +32 dBm output power, 1800 / 1900 MHz | | -101 | | dBc |
| 3rd harmonic | RFX-RFC | +18 dBm input power, 17-204 MHz | | -125 | | dBc |
| | | +32 dBm output power, 850 / 900 MHz | | -93 | | dBc |
| | | +32 dBm output power, 1800 / 1900 MHz | | -87 | | dBc |
| IMD3 | RF-RFC | Bands I, II, V, VIII +17 dBm CW @ TX freq at RFC, -15 dBm CW @ 2Tx-Rx at RFC, 50Ω | | -115 | | dBm |



| Parameter | Path | Condition | Min | Тур | Max | Unit |
|--|------------|---------------------------------------|-----|------------------|-----|-------------------|
| IIP2 | RFX | 5 MHz 17 MHz 100-6000 MHz | | 96 105 115 | | dBm dBm dBm |
| IIP3 | RFX | 5 MHz 17 MHz 100-6000 MHz | | 75 81 75 | | dBm dBm dBm |
| Input 0.1dB compression point ³ | RFX or RFC | 5-100 MHz 100-6000 MHz | | 33 34 | | dBm dBm |
| Switching time | | 50% CTRL to (10%-90%) or (90%-10%) RF | | 2 | 4 | μs |

Table 1. Electrical Specifications @ +25 °C¹, V_{DD} = 2.3-5.5V (Z_S = Z_L = 50 Ω), unless otherwise specified

Notes: 1. Typical performance over temperature and V_{DD} shown in *Figure 5* through *Figure 21*.

2. High frequency performance can be improved by external matching (see Figure 22 through Figure 27 and Figure 30).

3. The input P0.1dB compression point is a linearity figure of merit. Refer to Table 5 for the operating RF input power.

Switching Frequency

The PE42427 has a maximum 25 kHz switching frequency. Switching frequency describes the time duration between switching events. Switching time is the time duration between the point the control signal reached 50% of the final value and the point the output signal reaches within 10% or 90% of its target value.

Spurious Performance

The PE42427 spur fundamental occurs around 13 MHz. Its typical performance is -163 dBm/Hz, with 200 kHz bandwidth. The performance is ideally suited for cable broadband applications.

Pin 4 should also be left unconnected for optimal spurious performance.

Thermal Data

Psi-JT (Ψ_{JT}), junction top-of-package, is a thermal metric to estimate junction temperature of a device on the customer application PCB (JEDEC JESD51 -2).

 $\Psi_{JT} = (T_J - T_T)/P$

where

 Ψ_{JT} = junction-to-top of package characterization parameter, °C/W

 $T_J =$ die junction temperature, °C

 T_T = package temperature (top surface, in the center), °C

P = power dissipated by device, Watts

Table 2. Thermal Data for PE42427

| Parameter | Тур | Unit |
|---|-----|------|
| Y _{JT} | 48 | °C/W |
| Q_{JA} junction-to-ambient thermal resistance | 145 | °C/W |



Figure 3. Pin Configuration (Top View)

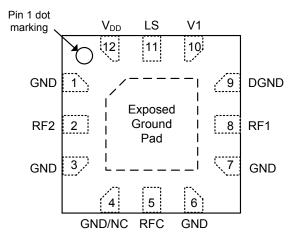


Table 3. Pin Descriptions

| Pin No. | Pin Name | Description |
|---------|---------------------|--|
| 1 | GND | Ground |
| 2 | RF2 ¹ | RF port 2 |
| 3 | GND | Ground |
| 4 | GND/NC ² | Ground or no connect |
| 5 | RFC ¹ | RF common |
| 6 | GND | Ground |
| 7 | GND | Ground |
| 8 | RF1 ¹ | RF port 1 |
| 9 | DGND | Digital Ground |
| 10 | V1 | Switch control input, CMOS logic level |
| 11 | LS | Logic Select, CMOS logic level |
| 12 | V _{DD} | Supply |
| Pad | GND | Exposed pad: ground for proper operation |

Notes: 1. RF pins 2, 5 and 8 must be at 0 VDC. The RF pins do not required DC blocking capacitors for proper operation if the 0 VDC requirement is met. 2. Pin 4 can be grounded or left unconnected externally.

Table 4. Truth Table

| Path | V1 | LS |
|---------|----|----|
| RFC-RF2 | 1 | 1 |
| RFC-RF1 | 0 | 1 |
| RFC-RF1 | 1 | 0 |
| RFC-RF2 | 0 | 0 |

Table 5. Operating Ranges

| Parameter | Min | Тур | Max | Unit |
|--------------------------------|-----|-----|--------|------|
| V _{DD} Supply voltage | 2.3 | 3.3 | 5.5 | V |
| IDD Power supply current | | 180 | 300 | μA |
| RFX-RFC input power | | | Fig. 4 | dBm |
| Control voltage high | 1.2 | 1.5 | 3.3 | V |
| Control voltage low | 0 | 0 | 0.5 | V |
| Operating temperature range | -40 | +25 | +95 | °C |

Table 6. Absolute Maximum Ratings

| Parameter/Condition | Min | Max | Unit |
|--|-----|--------------|------------|
| RF input power, 50Ω ¹ 5-100 MHz 100-6000 MHz | | 33 34 | dBm dBm |
| ESD voltage HBM ² RF pins to GND All other pins | | 4000 1000 | V V |
| ESD voltage MM, all pins ³ | | 200 | V |
| T _{ST} Storage temperature | -65 | +150 | °C |

Notes: 1. V_{DD} within operating range specified in *Table 5*.

Human Body Model (MIL_STD 883 Method 3015.7).
 Machine Model (JEDEC JESD22-A115-A).

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the *Operating Ranges* table.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

Latch-Up Avoidance

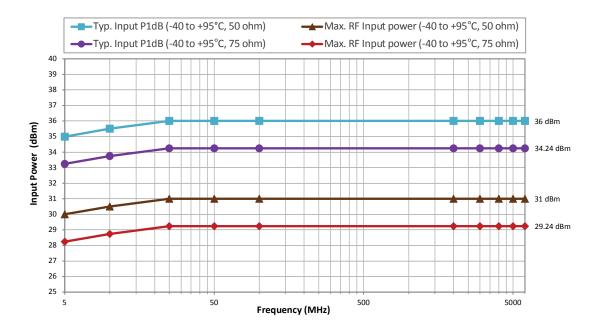
Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.

Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE42427 in the 12-lead $2 \times 2 \times 0.55$ mm QFN package is MSL1.



Figure 4. Power De-rating Curve for 5-6000 MHz





Typical Performance Data @ +25 $^\circ\text{C}$ and V_{DD} = 3.3V, unless otherwise specified

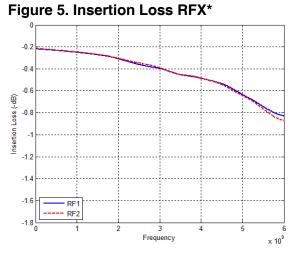


Figure 6. Insertion Loss vs Temp (RF1-RFC)*

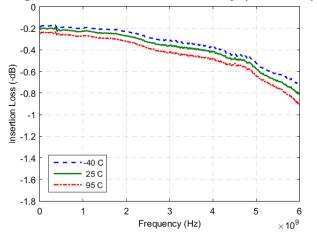
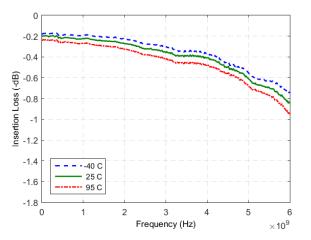


Figure 7. Insertion Loss vs Temp (RF2-RFC)*



Note: * High frequency performance can be improved by external matching (see Figure 22 through Figure 27 and Figure 30).

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Figure 8. Insertion Loss vs V_{DD} (RF1-RFC)*

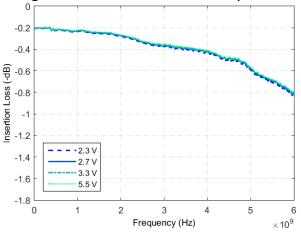
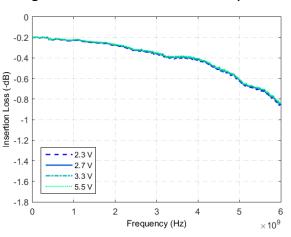


Figure 9. Insertion Loss vs V_{DD} (RF2-RFC)*





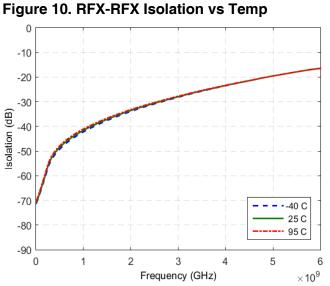


Figure 11. RFC-RFX Isolation vs Temp

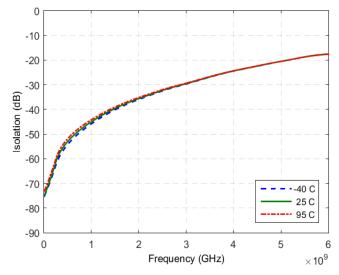
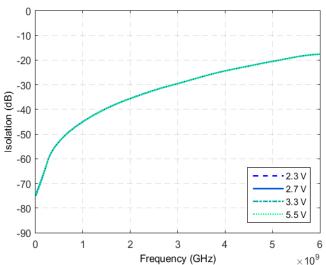


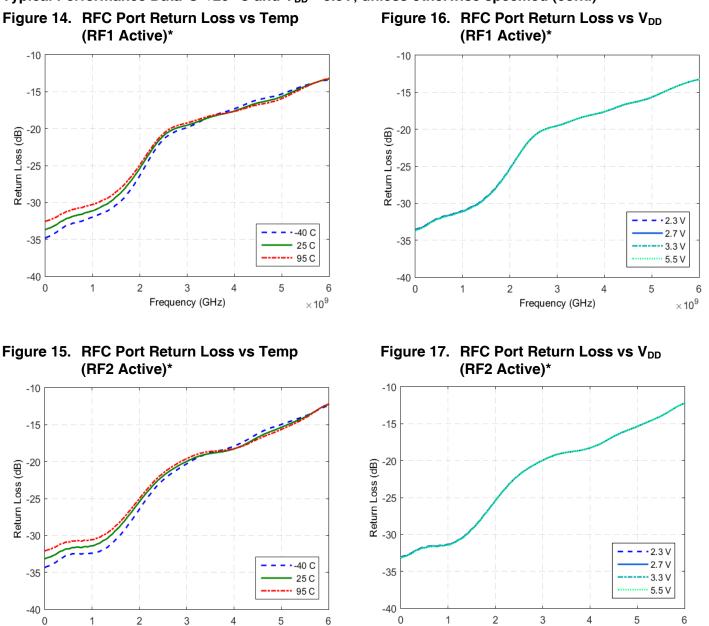
Figure 12. RFX-RFX Isolation vs V_{DD} 0 -10 -20 -30 Isolation (dB) -40 -50 -60 - 2.3 V -70 2.7 V • 3.3 V -80 5.5 V -90 2 3 0 1 4 5 6 $imes 10^9$ Frequency (GHz)

Figure 13. RFC-RFX Isolation vs V_{DD}



Typical Performance Data @ +25 °C and V_{DD} = 3.3V, unless otherwise specified (cont.)





Note: * High frequency performance can be improved by external matching (see Figure 22 through Figure 27 and Figure 30).

Frequency (GHz)

 $imes 10^9$

Frequency (GHz)

 $imes 10^9$



Typical Performance Data @ +25 °C and V_{DD} = 3.3V, unless otherwise specified (cont.)

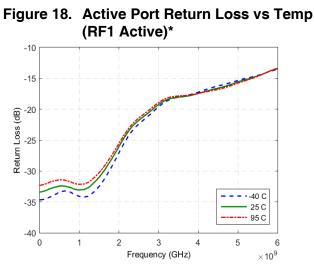
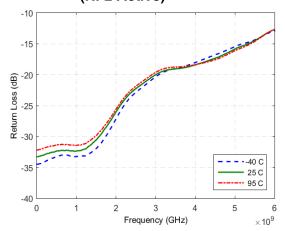


Figure 19. Active Port Return Loss vs Temp (RF2 Active)*



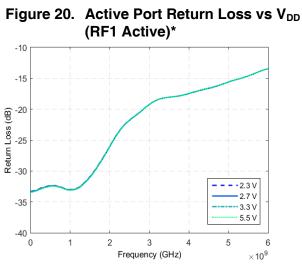
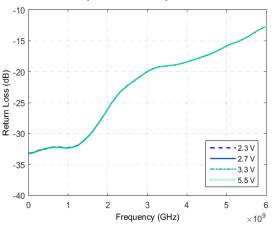


Figure 21. Active Port Return Loss vs V_{DD} (RF2 Active)*



Note: * High frequency performance can be improved by external matching (see Figure 22 through Figure 27 and Figure 30).



Performance Comparison @ +25 °C and V_{DD} = 3.3V, with or without matching

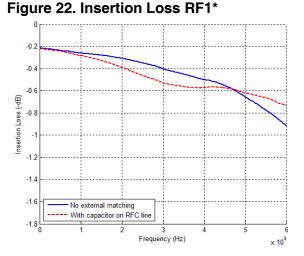


Figure 23. Active Port Return Loss (RF1 Active)*

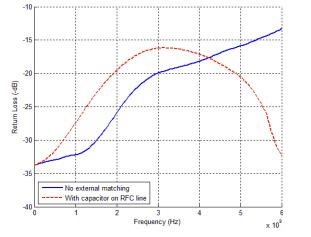
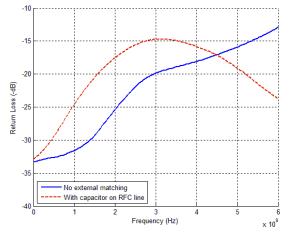
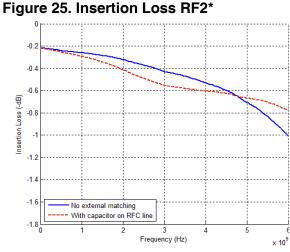


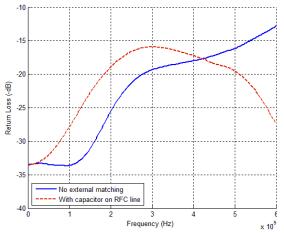
Figure 24. RFC Port Return Loss (RF1 Active)*



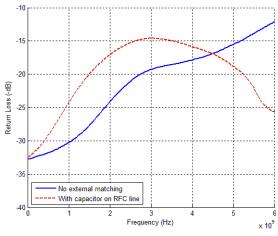
Note: * High frequency performance can be improved by external matching (see *Figure 22* through *Figure 27* and *Figure 30*).











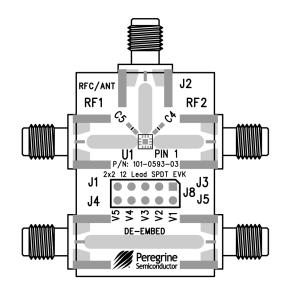


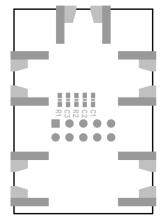
Evaluation Board

The SPDT switch evaluation board was designed to ease customer evaluation of pSemi's PE42427. The RF common port is connected through a 50Ω transmission line via the top SMA connector, J2. RF1 and RF2 ports are connected through 50Ω transmission lines via SMA connectors J1 and J3, respectively. A through 50Ω transmission is available via SMA connectors J4 and J5. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated. J8 provides DC and digital inputs to the device.

The board is constructed of a four metal layer material with a total thickness of 62 mils. The top and bottom RF layers are Rogers RO4350 material with a 10 mil RF core. The middle layers provide ground for the transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 22 mils, trace gaps of 7 mils, and metal thickness of 2.1 mils.

Figure 28. Evaluation Board Layout

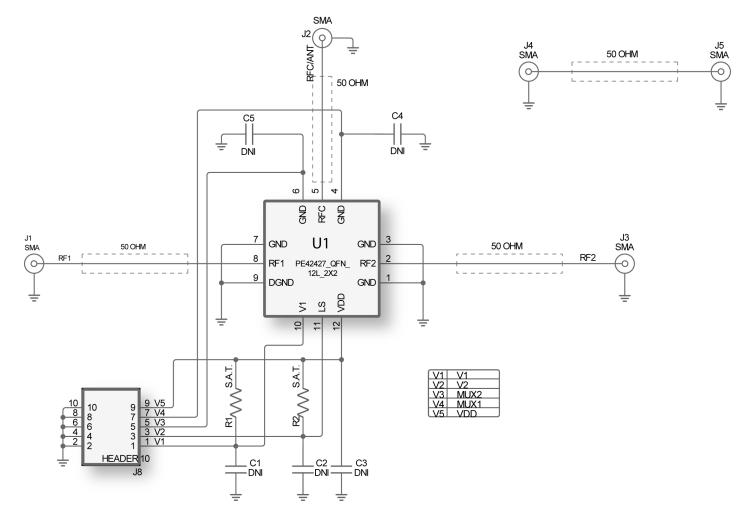




PRT-29005



Figure 29. Evaluation Board Schematic







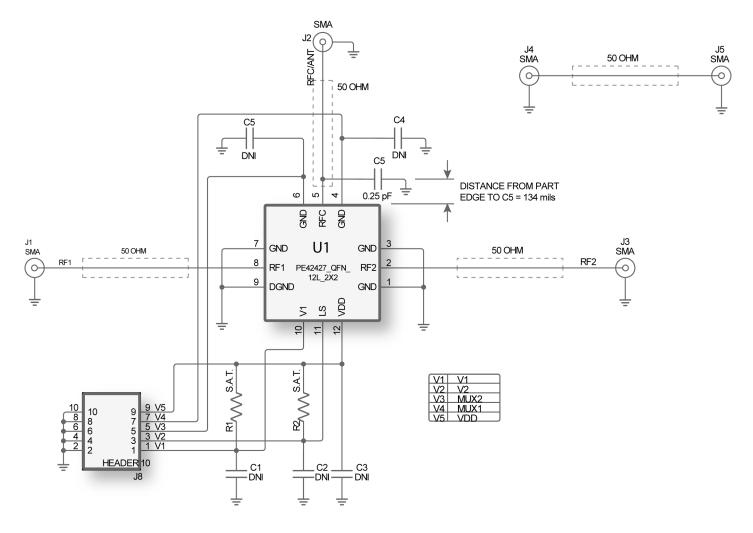
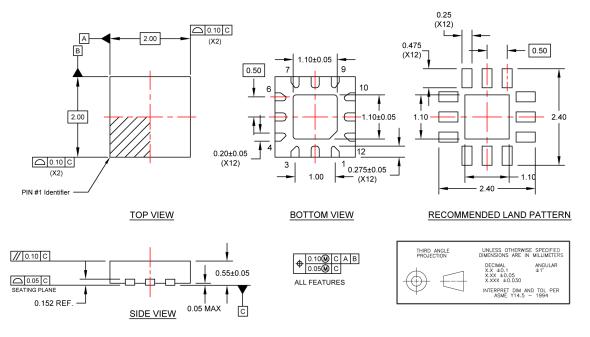




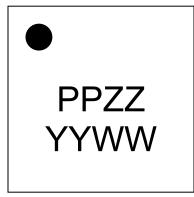
Figure 31. Package Drawing 12-lead 2 × 2 × 0.55 mm QFN



12L_2x2x0-55_QFN_DOC-01882-3



Figure 32. Top Marking Specifications



| Marking Spec Symbol | Package Marking | Definition |
|------------------------|--------------------|---|
| PP | EL | Part number marking for PE42427 |
| ZZ | 00-99 | Last two digits of lot code |
| YY 00-99 | | Last two digits of assembly year (Ex: 15 for 2015) |
| ww | 01-53 | Work week |

DOC-66046





Figure 33. Tape and Reel Specifications

12-lead 2 × 2 × 0.55 mm QFN

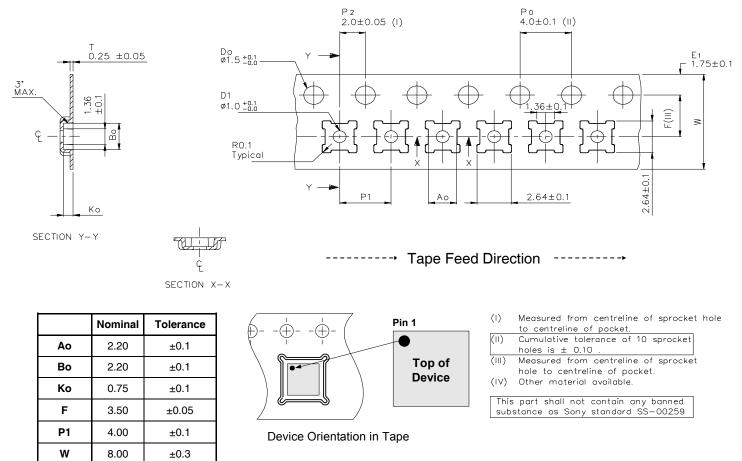


Table 6. Ordering Information

| Order Code | Description | Package | Shipping Method | |
|------------|--------------------------|---------------------------|-----------------|--|
| PE42427A-Z | PE42427 SPDT RF switch | Green 12-lead 2 × 2mm QFN | 3000 units T/R | |
| EK42427-01 | PE42427 Evaluation board | Evaluation kit | 1/Box | |

Sales Contact and Information

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 00600P0005
 00-9050-LRPP
 00-9090-RDPP
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 LVP640
 0158-624-00
 5J0-1000LG-SIL
 020017-13

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 LY2-0-US-AC120
 LY2-US-AC240
 LY3-UA-DC24
 00-5150
 00576P0020
 00600P0010
 LZNQ2M-US-DC5
 LZNQ2

 US-DC12
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 00-8274-RDPP
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